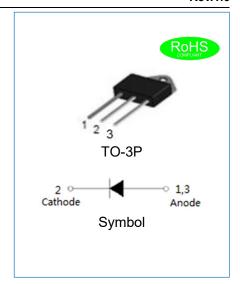
JIEJIE MICROELECTRONICS CO., LTD.

JECR7506ZW EPI HYPERFAST SOFT RECOVERY RECTIFIER

Rev.1.0

DESCRIPTION

- Plastic package has underwriters laboratory flammability classification 94V-0
- ♦ Lead free in comply with EU RoHS 2011/65/EU directives
- ♦ Low reverse leakage current
- ♦ Ultrafast recovery time and soft recovery characteristics
- ♦ Low recovery loss
- Active PFC in air conditioner, S.M.P.S Power Factor Correction (PFC) and half bridge/full-bridge switched-mode power supplies



MECHANICAL DATA

- Case: TO-3P molded plastic over passivated junction
- ♦ Terminals: Solder plated, solderable per J-STD-002
- ♦ Internally constructed isolated package is offered for ease of heat sinking with highest isolation voltage

ABSOLUTE MAXIMUM RATING (Rating at 25℃ case temperature unless otherwise specified.)

Parameter	Symbol	JECR7506ZW	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	600	V
Maximum RMS voltage	V _{RMS}	420	V
Maximum DC blocking voltage	V _{DC}	600	V
Maximum average forward current at Tc=70℃	I _{F(AV)}	75	Α
Peak forward surge current: 10ms single half sine-wave superimposed on rated load	, 700		^
Peak forward surge current: 8.3ms single half sine-wave superimposed on rated load	IFSM	750	A
Junction temperature and storage temperature range	T_j, T_{stg}	-55 to +150	$^{\circ}$ C

ISOLATION CHARACTERISTICS

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _{isol(RMS)}	RMS isolation voltage	50Hz≤f≤60Hz;RH≤65%;from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C _{isol}	Isolation capacitance	from cathode to external heatsink	-	10	1	pF



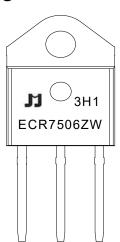
ELECTRICAL CHARACTERISTICS(Rating at 25° C case temperature unless otherwise specified.)

Parameter			Min.	Тур.	Max.	Unit
Commend valte as	I _F =75A,T _j =25℃		-	2.0	2.75	V
Forward voltage	I _F =75A,T _j =150℃	VF	V _F		2.1	V
Davena aument	V _R =600V,T _j =25°C				5	
Reverse current	V _R =600V,T _j =150℃	- I _R	-	-	500	μA
	I_F =1A,V _R =30V, di/dt=50A/ μ s,T $_j$ =25 $^{\circ}$ C		-	-	50	ns
Reverse recovery time	I _F =75A,V _R =400V, di/dt=200A/μs,Τ _j =25°C	t _{rr}	-	50	-	
	I _F =75A,V _R =400V, di/dt=200A/μs,Τ _j =125°C		-	110	-	
Dools massage management assume at	I _F =75A,V _R =400V, di/dt=200A/μs,T _j =25°C		-	4.5	-	٨
Peak reverse recovery current	I _F =75A,V _R =400V, di/dt=200A/μs,Τ _j =125°C	I _{RM}	-	14	-	Α
_	I _F =75A,V _R =400V, di/dt=200A/μs,T _j =25°C	_	-	150	-	" C
Reverse charge	I _F =75A,V _R =400V, di/dt=200A/μs,T _j =125°C	Q _r		650	-	nC

THERMAL RESISTANCES

Symbo	Parameter	Min.	Тур.	Max.	Unit
R _{th(j-c)}	Thermal resistance from junction to case	-	0.9	-	°C/W

MARKING



ECR	EPI Hyperfast Recovery Rectifier
75	I _{F(AV)} =75A
06	V _{RRM} :600V
ZW	Package:TO-3P

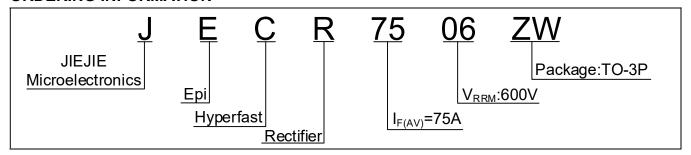
 $\underline{\boldsymbol{x}} H1 \boldsymbol{.}$ Month, 1, 2, 3 \sim 9, A, B, C

3<u>x</u>1:

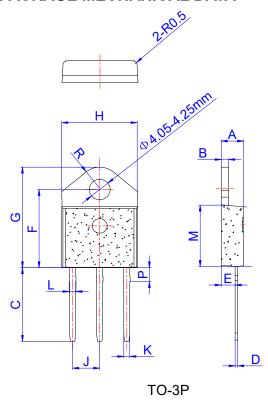
2018	2019	2020	2021	2022	2023	2024
Н	I	J	K	L	М	N
2025	2026	2027	2028	2029	2030	
0	Р	Q	R	S	Т	

3Hx: Batch number

ORDERING INFORMATION



PACKAGE MECHANICAL DATA



	Dimensions					
Ref.		Millimeters		Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	4.40		4.60	0.173		0.181
В	1.45		1.55	0.057		0.061
С	14.35		15.60	0.565		0.614
D	0.50		0.70	0.020		0.028
E	2.70		2.90	0.106		0.114
F	15.80		16.50	0.622		0.650
G	20.40		21.10	0.803		0.831
Н	15.10		15.50	0.594		0.610
J	5.40		5.65	0.213		0.222
K	1.10		1.40	0.043		0.055
L	1.35		1.50	0.053		0.059
М	12.37		12.77	0.487		0.503
Р	2.80		3.00	0.110		0.118
R		4.35			0.171	

PACKAGE INFORMATION-TO-3P

OUTLINE	UNIT WEIGHT (g/PCS) typ.	TUBE (PCS)	PER CARTON (PCS)
TUBE	4.805	30	2,250

CHARACTERITICS CURVE

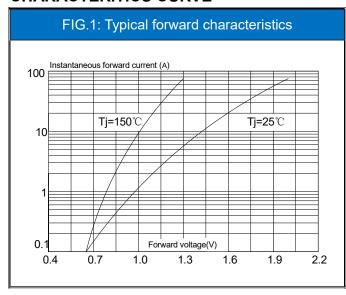
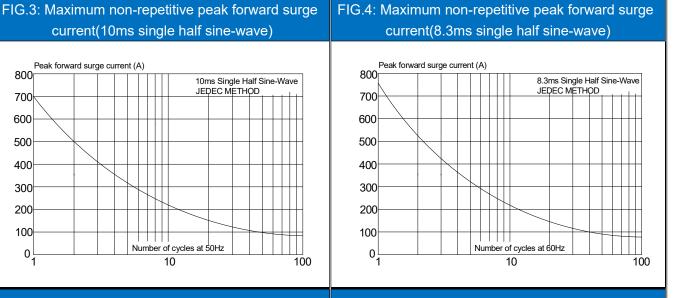
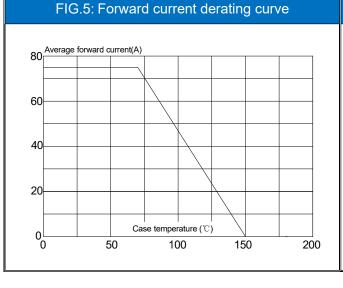
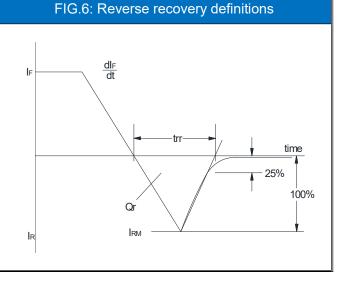


FIG.2: Typical reverse characteristics Instantaneous reverse current (µA) 1000 Tj=150℃ 100 10 1.0 Tj=25°C 0.1 Percentage of peak reverse voltage (%) 0.01 100 20 40 60

current(10ms single half sine-wave) Peak forward surge current (A) 800 10ms Single Half Sine-Wave JEDEC METHOD 700 600 500 400 300 200 100 Number of cycles at 50Hz 0 10 100









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